

## Application Data Sheet

### **Application Information**

Application Type:: Regular  
Subject Matter:: Utility  
Suggested Group Art Unit:: N/A  
CD-ROM or CD-R?:: None  
Sequence submission?:: None  
Computer Readable Form (CRF)?:: No  
Title:: PMOS DEVICE HAVING ULTRA  
SHALLOW SUPER-STEEP-RETROGRADE  
EPI-CHANNEL WITH DUAL CHANNEL  
DOPING AND METHOD FOR  
FABRICATING THE SAME  
Attorney Docket Number:: 29926/39497  
Request for Early Publication?:: No  
Request for Non-Publication?:: No  
Small Entity?:: No  
Petition included?:: No  
Secrecy Order in Parent Appl.?:: No

### **Applicant Information**

Applicant Authority Type:: Inventor  
Primary Citizenship Country:: Korea, Republic of  
Status:: Full Capacity  
Given Name:: Yong-sun  
Family Name:: Sohn  
City of Residence:: Kyoungki-Do  
Country of Residence:: Korea  
Street of mailing address:: #707-704 Kyungnam Apt., Yatap-dong,  
Bundang-gu, Sungnam-shi  
City of mailing address:: Kyoungki-Do

Country of mailing address:: Korea, Republic of  
Postal or Zip Code of mailing address:: 463-070

### **Correspondence Information**

Correspondence Customer Number:: 04743

### **Representative Information**

Representative Customer Number:: 04743

### **Foreign Priority Information**

Country::	Application number::	Filing Date::	Priority Claimed::
Korea, Republic of	2002-86275	12/30/02	Yes

### **Assignee Information**

Assignee name:: HYNIX SEMICONDUCTOR INC.  
Street of mailing address:: San 136-1, Ami-Ri, Bubal-Eub, Ichon-Shi  
City of mailing address:: Kyoungki-Do  
Country of mailing address:: Korea, Republic of  
Postal or Zip Code of mailing address:: 467-860